



April 2015

KSH44H11 / KSH44H11I

NPN Epitaxial Silicon Transistor

Features

- Lead Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "-I" Suffix)
- Electrically Similar to Popular KSE44H
- Fast Switching Speeds
- Low Collector-Emitter Saturation Voltage

Applications

- Switching Regulators
- Converters
- Power Amplifiers

Description

Designed for general-purpose power and switching, such as output or driver stages in applications.



Ordering Information

Part Number	Top Mark	Package	Packing Method
KSH44H11TF	KSH44H11	TO-252 3L (DPAK)	Tape and Reel
KSH44H11TM	KSH44H11	TO-252 3L (DPAK)	Tape and Reel
KSH44H11ITU	KSH44H11-I	TO-251 3L (IPAK)	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	8	A
I_{CP}	Collector Current (Pulse)	16	A
P_C	Collector Dissipation ($T_C = 25^\circ\text{C}$)	20.00	W
	Collector Dissipation ($T_A = 25^\circ\text{C}$)	1.75	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 to +150	$^\circ\text{C}$

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Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage ⁽¹⁾	$I_C = 30\text{ mA}, I_B = 0$	80			V
I_{CEO}	Collector Cut-Off Current	$V_{CE} = 80\text{ V}, I_B = 0$			10	μA
I_{EBO}	Emitter Cut-Off Current	$V_{EB} = 5\text{ V}, I_C = 0$			50	μA
h_{FE}	DC Current Gain	$V_{CE} = 1\text{ V}, I_C = 2\text{ A}$	60			
		$V_{CE} = 1\text{ V}, I_C = 4\text{ A}$	40			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 8\text{ A}, I_B = 0.4\text{ A}$			1	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 8\text{ A}, I_B = 0.8\text{ A}$			1.5	V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{ V}, I_C = 0.5\text{ A}$		50		MHz
C_{ob}	Output Capacitance	$V_{CB} = 10\text{ V}, f = 1\text{ MHz}$		130		pF
t_{ON}	Turn-On Time	$I_C = 5\text{ A},$ $I_{B1} = -I_{B2} = 0.5\text{ A}$		300		ns
t_{STG}	Storage Time			500		ns
t_F	Fall Time			140		ns

Note:

1. Pulse test: pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

Typical Performance Characteristics

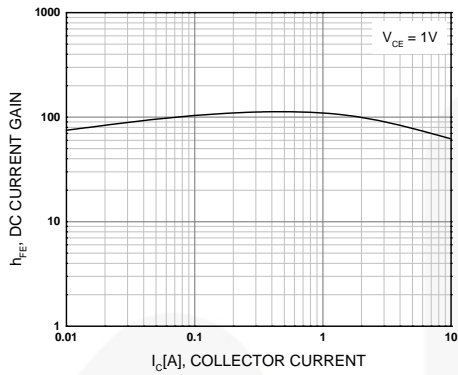


Figure 1. DC Current Gain

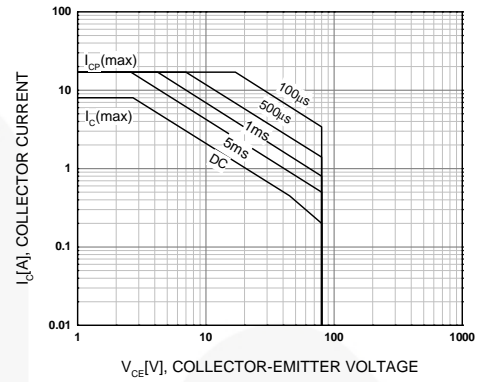


Figure 2. Safe Operating Area

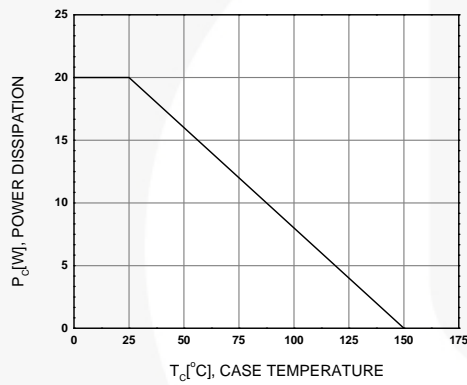
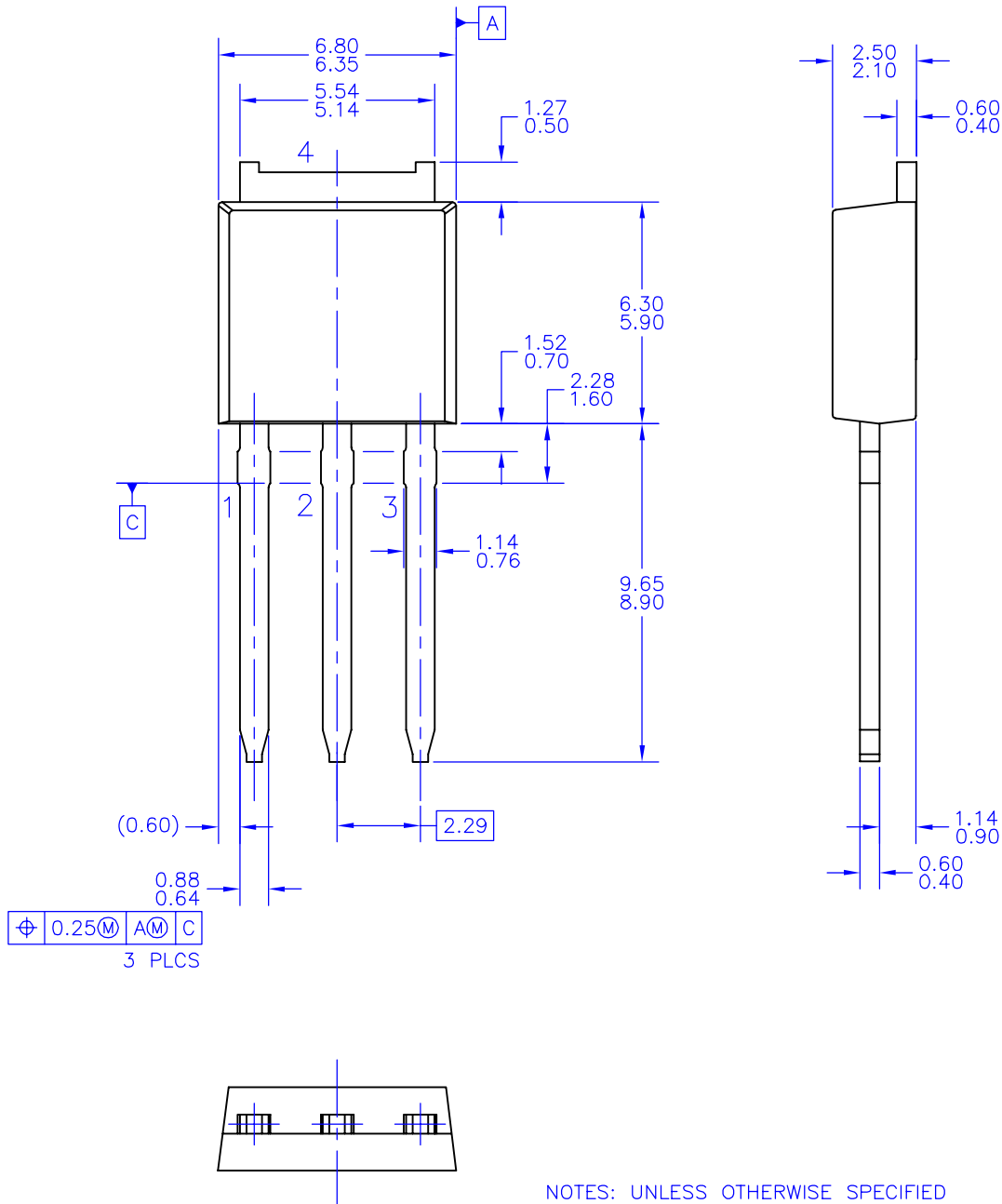


Figure 3. Power Derating

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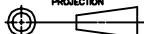
LTR	DESCRIPTION	E.C.N.	DATE	BY/APP'D
A	RELEASE TO DOCUMENT CONTROL	CB/031/01	16MAR2001	RM

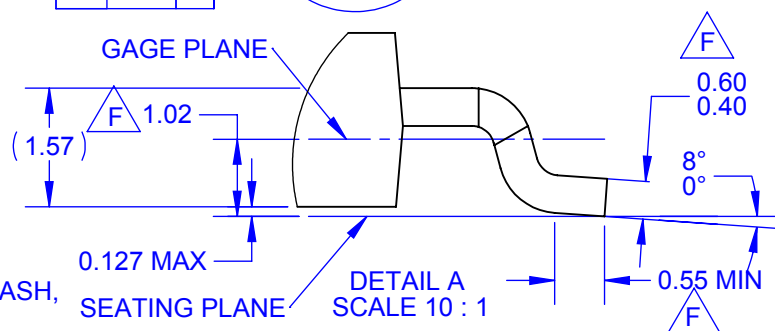
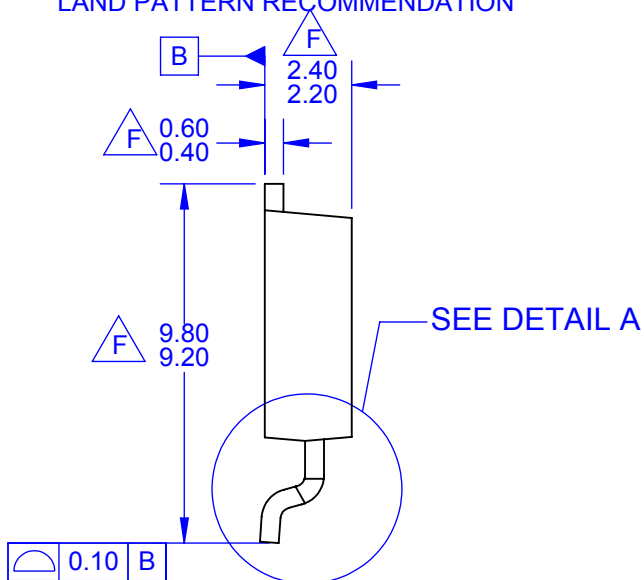
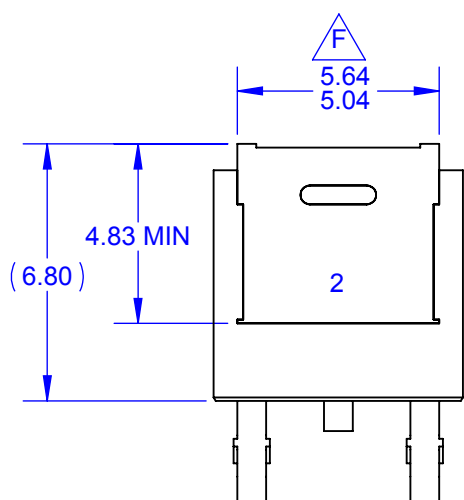
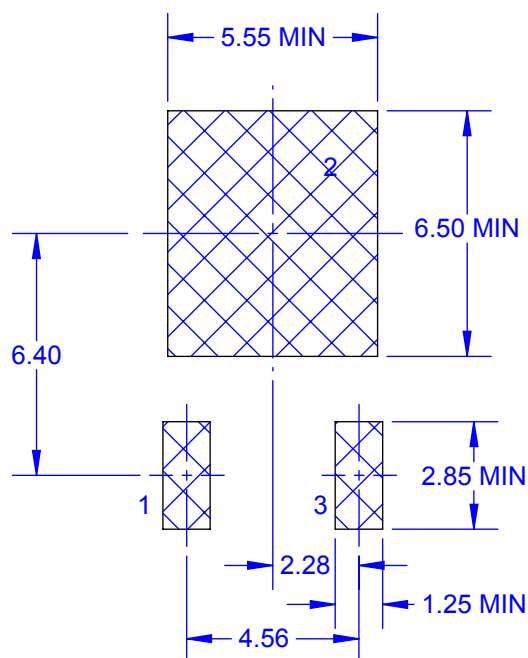


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- B) THIS PACKAGE CONFORMS TO JEDEC, TO-251, ISSUE C, VARIATION AA, DATED SEP 1988.
- C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

TO251A03REVA

APPROVALS		DATE		<div><div></div><div>FAIRCHILD</div><div></div><div>SEMICONDUCTOR™</div></div> <div>CEBU PHILIPPINES</div>	
DRAWN: J. GOMEZ		16MAR2001			
CHECKED: R. MANABIT					
APPROVED: M. GESTOLE					
G.S. BAJE				TO-251 (I-PAK) MOLDED, 3 LEAD, OPTION AA	
<div><div>PROJECTION</div><div></div><div>1st ANGLE</div></div>		SCALE		SIZE	
		8:1		A3	
		FORMERLY: N/A		DRAWING NUMBER	
				MKT-T0251A03	
				REV	
				A	
				SHEET : 1 OF 1	



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